

PHEMT GaAs IC High Linearity 3 V Control SPDT Switch 0.1–2.5 GHz



AS193-73

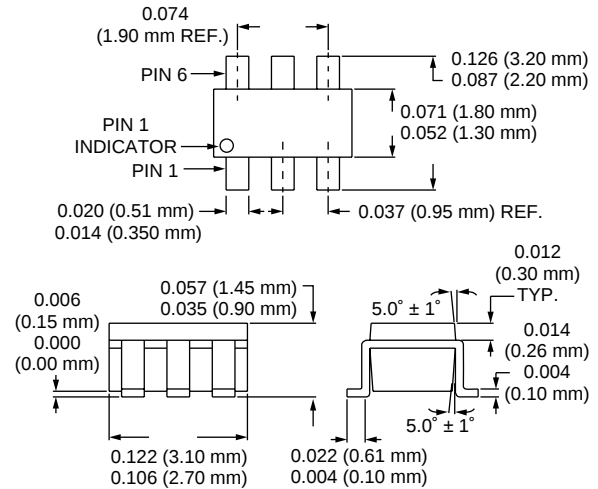
Features

- +2.5 to +5 V Linear Operation
- Harmonics $H_2, H_3 > 65$ dBc @
 $P_{IN} = 34.5$ dBm
- Low Insertion Loss (0.35 dB @ 0.9 GHz)
- High Isolation (24 dB @ 0.9 GHz)
- Ultra Miniature SOT-6 Package
- PHEMT Process

Description

The AS193-73 is a PHEMT GaAs FET IC high linearity SPDT switch in a SOT-6 plastic package. This switch has been designed for use where extremely high linearity, low control voltage, high isolation, low insertion loss and ultra miniature package size are required. It can be controlled with positive, negative or a combination of both voltages. Some standard implementations include antenna changeover, T/R and diversity switching over 3 W. The

SOT-6



AS193-73 switch can be used in many analog and digital wireless communication systems including cellular, GSM and UMTS applications.

Electrical Specifications at 25°C (0, +3 V)

Parameter ¹	Frequency	Min.	Typ.	Max.	Unit
Insertion Loss ²	0.1–0.5 GHz		0.30	0.4	dB
	0.5–1.0 GHz		0.35	0.5	dB
	1.0–2.0 GHz		0.45	0.6	dB
	2.0–2.5 GHz		0.55	0.7	dB
Isolation	0.1–0.5 GHz	28	30		dB
	0.5–1.0 GHz	22	24		dB
	1.0–2.0 GHz	17	19		dB
	2.0–2.5 GHz	15	17		dB
VSWR ³	0.1–1.0 GHz		1.2:1		dB
	1.0–2.5 GHz		1.3:1		dB

Operating Characteristics at 25°C (0, +3 V)

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁴	Rise, Fall (10/90% or 90/10% RF)			60		ns
	On, Off (50% CTL to 90/10% RF)			100		ns
	Video Feedthru			50		mV
Input Power for -0.1 dB Compression	0/+3 V	0.9 GHz		+37		dBm
Harmonics H_2, H_3	$P_{IN} = 34.5$ dBm	0.9 GHz		+65		dBc
Control Voltages	$V_{Low} = 0$ to 0.2 V @ 20 μ A Max. $V_{High} = +2.5$ V @ 100 μ A Max. to +5 V @ 200 μ A Max.					

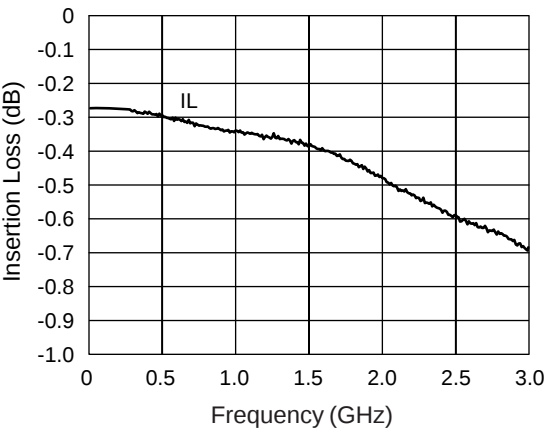
1. All measurements made in a 50 Ω system, unless otherwise specified.

2. Insertion loss changes by 0.003 dB/°C.

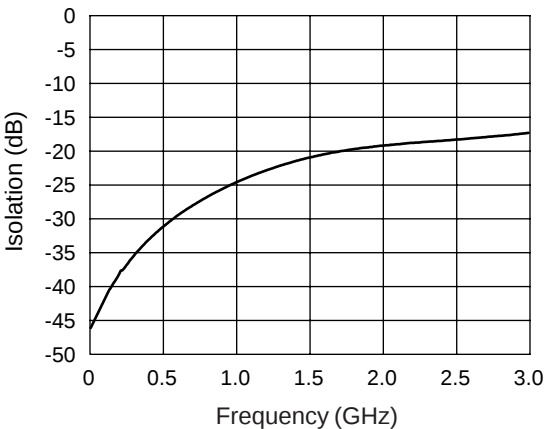
3. Insertion loss state.

4. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

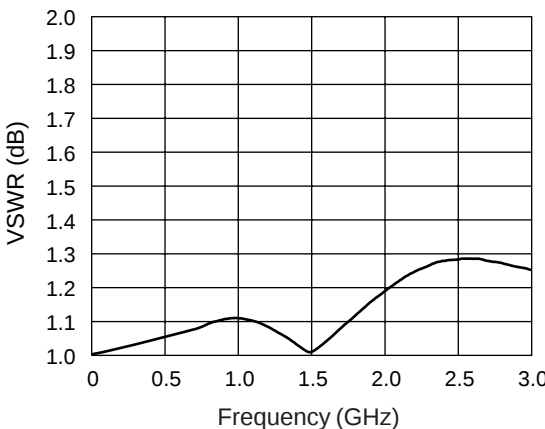
Typical Performance Data



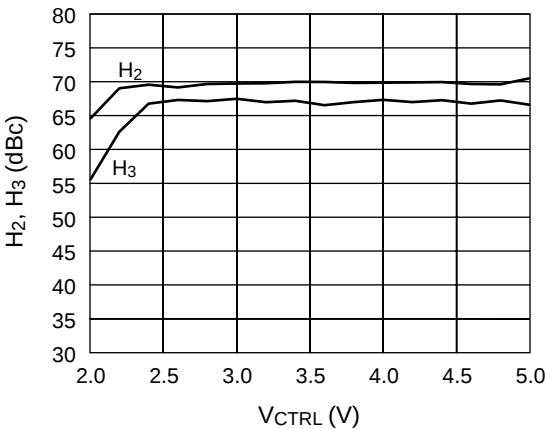
Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency



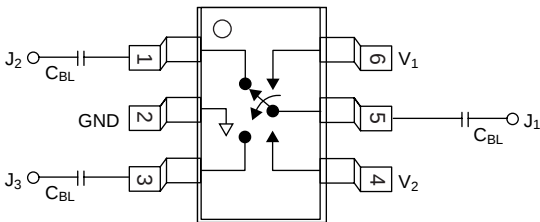
AS193-73 Harmonics vs. Control Voltage
P_{IN} = 34.5 dBm, 900 MHz, GSM Pulsed

Truth Table

V ₁	V ₂	J ₁ –J ₂	J ₁ –J ₃
0	V _{High}	Isolation	Insertion Loss
V _{High}	0	Insertion Loss	Isolation

V_{High} = +2.5 to +5 V.

Pin Out



DC blocking capacitors (C_{BL}) must be supplied externally.
C_{BL} = 100 pF for operating frequency >500 MHz.

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	6 W Max. > 900 MHz, 0/+5 V Control
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Θ _{JC}	25°C/W